

MCR101-MCR104 SERIES

High-reliability discrete products and engineering services since 1977

SILICON CONTROLLED RECTIFIERS

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS.

Rating	Symbol	Value	Unit
Peak reverse blocking voltage			
MCR101		15	
MCR102	V_{RRM}	30	Volts
MCR103		60	
MCR104		100	
Forward current RMS (all conduction angles)	I _{T(RMS)}	0.8	Amps
Peak forward surge current (1/2 cycle, sine wave 60 Hz, T _A = 25°C)	I _{TSM}	6.0	Amps
Circuit fusing considerations (t = 1 to 8.3ms, T _A = 25°C)	I ² t	0.15	A ² s
Forward peak gate power (T _A = 25°C)	P _{GM}	0.1	Watts
Forward average gate power (T _A = 25°C)	P _{G(AV)}	0.01	Watts
Forward peak gate current (T _A = 25°C, 300µs, 120PPS)	I _{GM}	1.0	Amps
Reverse peak gate voltage	V_{GM}	4.0	Volts
Operating junction temperature range @ rated V _{RRM} and V _{DRM}	T,	-65 to +85	°C
Storage temperature range	T_{stg}	-65 to +150	°C
Lead solder temperature (<1/16" from case, 10 sec. max.)	-	+230	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal resistance, junction-to-case	R _{ÐJC}	75	°C/W
Thermal resistance, junction-to-ambient	R _{eJA}	200	°C/W

ELECTRICAL CHARACTERISTICS (T₁ = 25°C unless otherwise specified)

Characteristic	Symbol	Min	Max	Unit
Peak forward blocking voltage ⁽¹⁾ (T _C = 85°C)				
MCR101		15	-	
MCR102	V _{DRM}	30	-	Volts
MCR103		60	-	
MCR104		100	-	
Peak forward blocking current (Rated V _{DRM} @ T _C = 85°C)	I _{DRM}	-	100	μΑ
Peak reverse blocking current (Rated V _{RRM} @ T _C = 85°C)	I _{RRM}	-	100	μΑ
Forward "on" voltage ⁽²⁾ (I _{TM} = 1.0A peak @ T _A = 25°C)	V _{TM}	-	1.7	Volts
Gate trigger current (continuous dc) ⁽³⁾ ($V_{AK} = 7Vdc$, $R_L = 100\Omega$, $T_C = 25$ °C)	I _{GT}	-	200	μΑ
Gate trigger voltage (continuous dc) ($V_{AK} = 7Vdc$, $R_L = 100\Omega$)				
T _C = 25°C	V_{GT}	-	0.8	Volte
T _C = -65°C		-	1.2	Volts
T _C = 85°C	V_{GD}	0.1	-	
Holding current (V _{AK} = 7Vdc, initiating current = 20mA)				4
T _C = 25°C	I _H	-	5.0	mA
T _C = -65°C		-	10	



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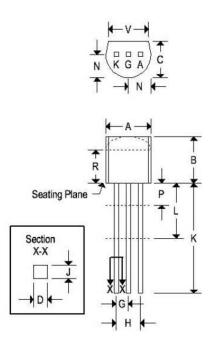
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Note 1: V_{DRM} and V_{RRM} for all types can be applied on a continuous dc basis without incurring damage. Ratings apply for zero or negative gate voltage but positive gate voltage shall not be applied concurrently with a negative potential on the anode. When checking forward or reverse blocking capability, thyristor devices should not be tested with a constant current source in a manner that the voltage applied exceeds the rated blocking voltage. Note 2: Forward current applied for 1.0 ms maximum duration, duty cycle $\leq 1.0\%$. Note 3: R_{GK} current is not included in measurement.

MECHANICAL CHARACTERISTICS

Case:	TO-92
Marking:	Body painted, alpha-numeric
Pin out:	See below



	TO-92				
	Inches		Millimeters		
	Min	Max	Min	Max	
Α	0.175	0.205	4.450	5.200	
В	0.170	0.210	4.320	5.330	
С	0.125	0.165	3.180	4.190	
D	0.016	0.022	0.410	0.550	
F	0.016	0.019	0.410	0.480	
G	0.045	0.055	1.150	1.390	
Н	0.095	0.105	2.420	2.660	
J	0.015	0.020	0.390	0.500	
K	0.500	7	12.700	-	
L	0.250	376	6.350	188	
N	0.080	0.105	2.040	2.660	
Р	- 2	0.100	-	2.540	
R	0.115	199	2.930	199	
٧	0.135	- 2	3.430	723	



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FIGURE 1 – CURRENT DERATING (REFERENCE: CASE TEMPERATURE)

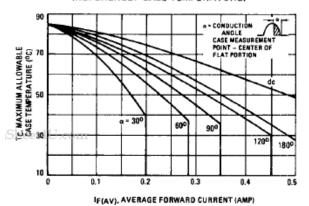
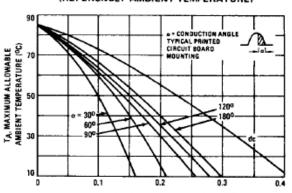


FIGURE 2 - CURRENT DERATING (REFERENCE: AMBIENT TEMPERATURE)



IF(AV), AVERAGE FORWARD CURRENT (AMP)